

描述 / Descriptions

SOT-23 塑封封装 P 道 MOS 场效应管。 P- CHANNEL MOSFET in a SOT-23 Plastic Package.

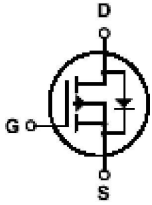
特征 / Features

沟道场效应管, MOS 场效应管。
Trench FET Power MOSFET 100% Rg Tested.

用途 / Applications

主要用于显示屏驱动。
Primarily the display screen drive applications.

内部等效电路 / Equivalent Circuit



引脚排列 / Pinning



PIN1: S PIN 2: G PIN 3: D

印章代码 / Marking

Marking	A1SHB
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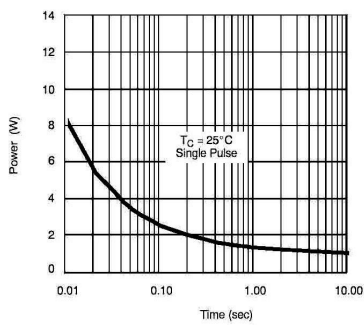
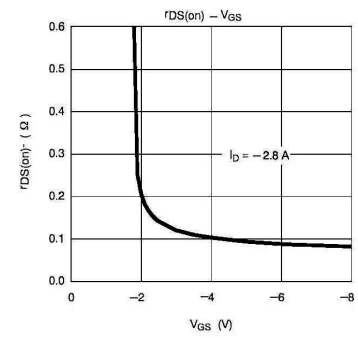
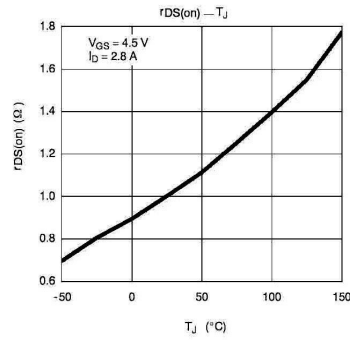
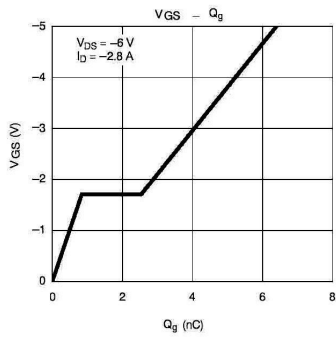
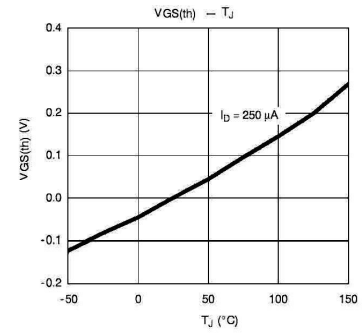
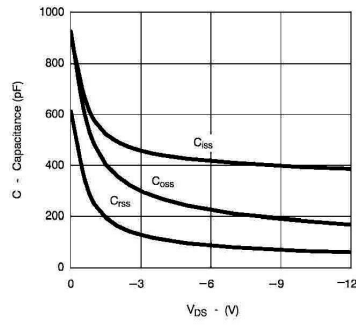
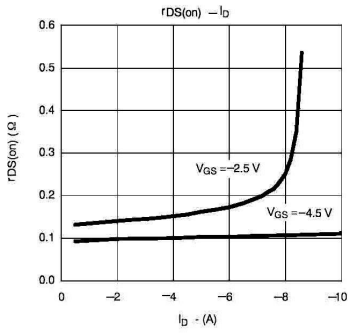
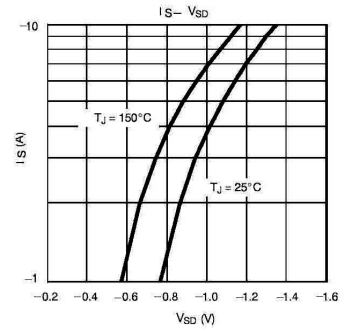
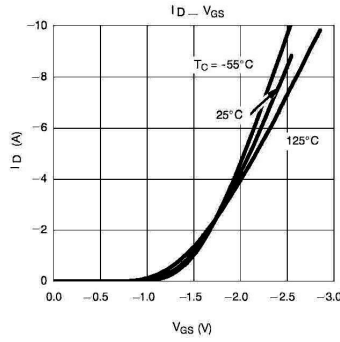
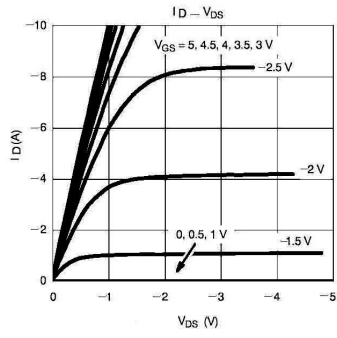
极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	V_{DSS}	-20	V
Gate-Source Voltage	V_{GSS}	±8	V
Drain Current – Continuous	I_D	-2.8	A
Drain Current – Continuous	$I_D(T_A=70^\circ\text{C})$	-1.5	A
Pulsed Drain Current	I_{DM}	-10	A
Continuous Source Current (Diode Conduction)	I_S	-1.6	A
Power Dissipation	P_D	1.25	W
Power Dissipation	$P_D(T_A=70^\circ\text{C})$	0.8	W
Storage Temperature Range	T_{stg}	-55~150	°C

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-20			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-0.45		-0.95	V
Static Drain-Source On-Resistance	$R_{DS(on)1}$	$V_{GS}=-4.5V$ $I_D=-2.8A$		0.105	0.13	Ω
	$R_{DS(on)2}$	$V_{GS}=-2.5V$ $I_D=-2.0A$		0.145	0.19	Ω
Zero Gate Voltage Drain Current	$I_{DSS(1)}$	$V_{DS}=-20V$ $V_{GS}=0V$			-1	μA
	$I_{DSS(2)}$	$V_{DS}=-20V$ $V_{GS}=0V$ $T_j=55^\circ\text{C}$			-10	μA
Gate-Body Leakage	I_{GSS}	$V_{GS}=\pm 8V$ $V_{DS}=0V$			±0.1	μA
State Drain Current	$I_{D(1)}$	$V_{DS}\leq -5V$ $V_{GS}=-4.5V$	-6			A
	$I_{D(2)}$	$V_{DS}\leq -5V$ $V_{GS}=-2.5V$	-3			A
Drain-Source Diode Forward Voltage	V_{SD}	$I_S=-1.6A$ $V_{GS}=0V$		-0.8	-1.2	V
Forward Transconductance	g_{FS}	$V_{DS}=-5V$ $I_D=-2.8A$		6.5		S
Input Capacitance	C_{iss}	$V_{DS}=-6V$ $V_{GS}=0$ $f=1\text{MHz}$		415		pF
Output Capacitance	C_{oss}			223		
Reverse Transfer Capacitance	C_{rss}			84		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-6V$ $R_L=6\Omega$ $R_G=6\Omega$ $I_D\approx -1A$ $V_{GEN}=-4.5V$		13	25	ns
Turn-On Rise Time	t_r			36	60	
Turn-Off Delay Time	$t_{d(off)}$			42	70	
Turn-Off Fall Time	t_f			34	60	

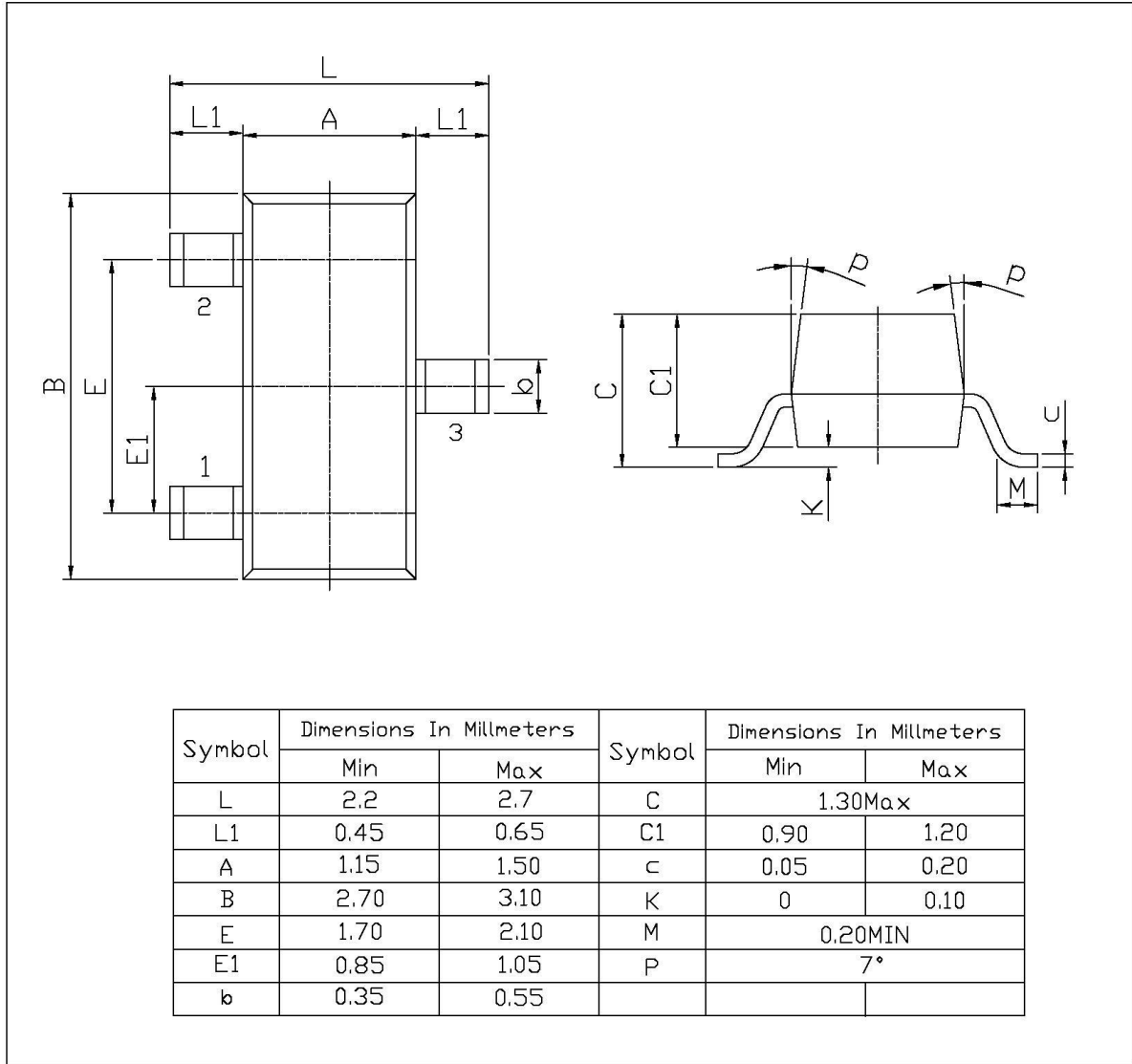
电参数曲线图 / Electrical Characteristic Curve



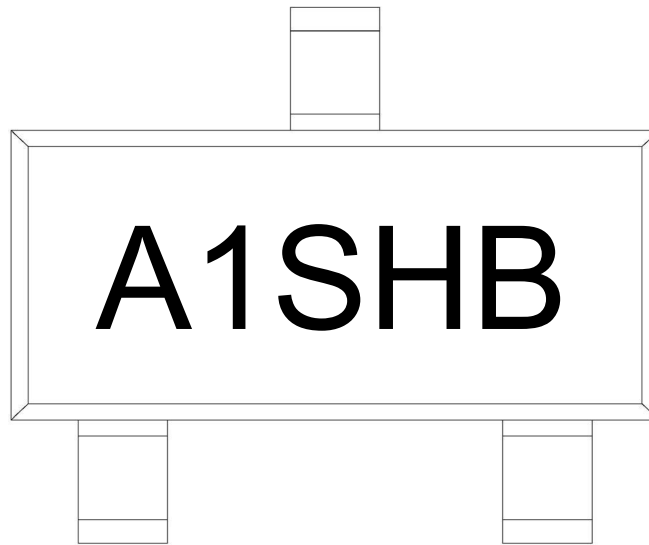
外形尺寸图 / Package Dimensions

SOT-23

单位; mm



印章说明 / Marking Instructions



说明:

A1: 为型号代码

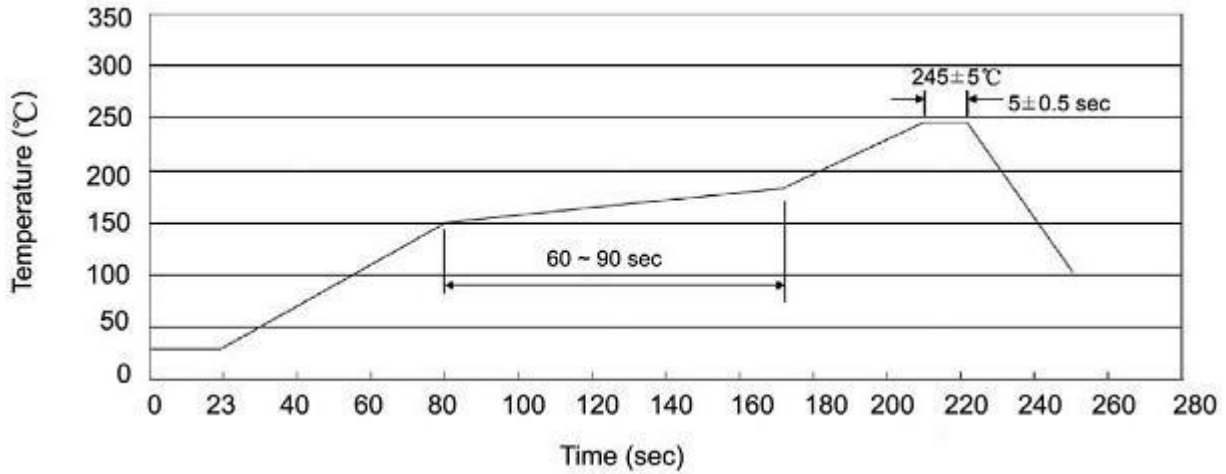
SHB: 为公司代码

Note:

A1: Product Type

SHB: Company Code.

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)



说明:

- 1、预热温度 25 ~ 150°C, 时间 60 ~ 90sec;
- 2、峰值温度 245±5°C, 时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度: 260±5°C

时间: 10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	8	240,000	7" ×8	180×120×180	385×257×392

使用说明 / Notices